

SANYO Semiconductors DATA SHEET

2SJ635 — General-Purpose Switching Device Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 4V drive.
- · DC / DC Converter.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		-60	V
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		-12	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-48	Α
Allowable Power Dissipation	PD		1	W
	ا ا	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			l lait
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-60V, V _{GS} =0V			-1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-1mA	-1.2		-2.6	V
Forward Transfer Admittance	yfs	V _{DS} =-10V, I _D =-6A	9	13		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-6A, V _G S=-10V		45	60	mΩ
	RDS(on)2	ID=-6A, VGS=-4V		65	92	mΩ
Input Capacitance	Ciss	V _{DS} =-20V, f=1MHz		2200		pF
Output Capacitance	Coss	V _{DS} =-20V, f=1MHz		235		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-20V, f=1MHz		165		pF

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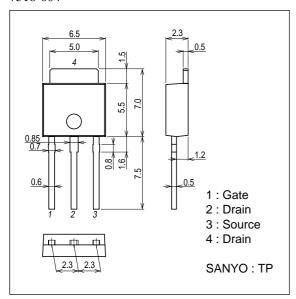
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Office
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		18		ns
Rise Time	t _r	See specified Test Circuit.		80		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		200		ns
Fall Time	tf	See specified Test Circuit.		125		ns
Total Gate Charge	Qg	V _{DS} =-30V, V _{GS} =-10V, I _D =-12A		45		nC
Gate-to-Source Charge	Qgs	V _D S=-30V, V _G S=-10V, I _D =-12A		10		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-30V, V _{GS} =-10V, I _D =-12A		7		nC
Diode Forward Voltage	V _{SD}	I _S =-12A, V _{GS} =0V		-0.9	-1.2	V

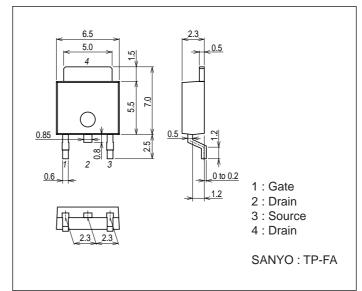
Package Dimensions

unit : mm 7518-004

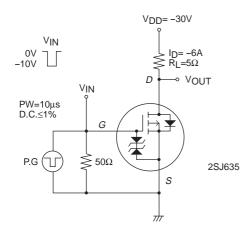


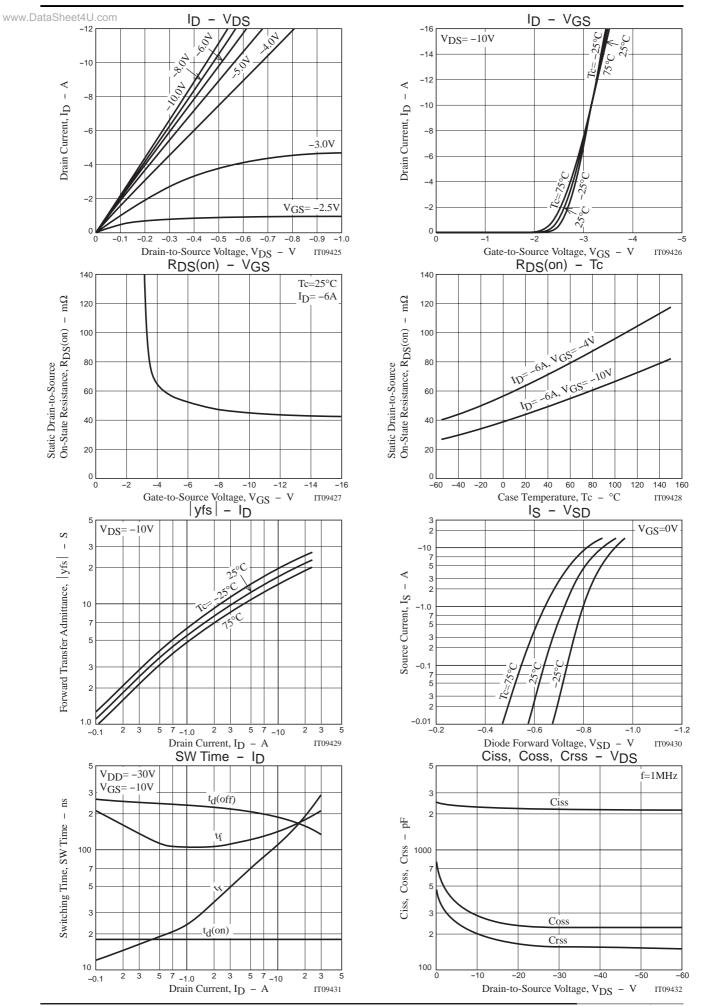
Package Dimensions

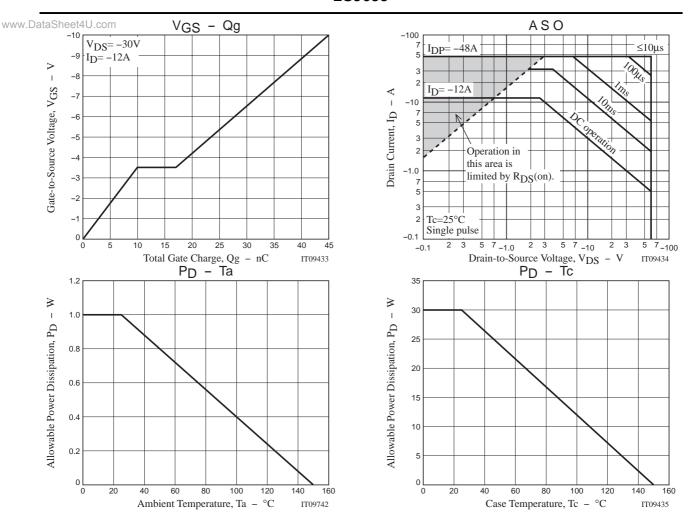
unit : mm 7003-004



Switching Time Test Circuit







Note on usage: Since the 2SJ635 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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